GMGarboMicro Semiconductor

DB151S thru DB157S

SURFACE MOUNT GLASS PASSIVATED BRIDGE RECTIFIERS

REVERSE VOLTAGE - **50** to **1000**Volts FORWARD CURRENT - **1.5** Ampere

FEATURES

- Rating to 1000V PRV
- Ideal for printed circuit board
- ●Low forward voltage drop,high current capability
- Reliable low cost construction utilizing molded plastic technique results in inexpensive product
- •The plastic material has UL flammability

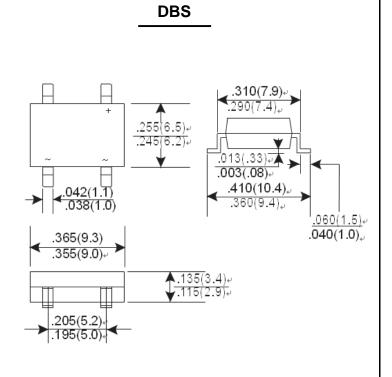
classification 94V-0

MECHANICAL DATA

Polarit:As marked on Body

Mounting position: Any

•Weight:0.02 ounces,0.38 grams



Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating at 25°C ambient temperature unless otherwise specified.

Single phase, half wave ,60Hz, resistive or inductive load.

For capacitive load, derate current by 20%

CHARACTERISTICS	SYMBOL	DB151S	DB152S	DB153S	DB154S	DB155S	DB156S	DB157S	UNIT
Maximum Recurrent Peak Reverse Voltage	Vrrm	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	VRMS	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	VDC	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Current @Ta=40°C	l(AV)	1.5							А
Peak Forward Surge Current 8.3ms Single Half Sine-Wave Super Imposed on Rated Load (JEDEC Method)	IFSM	30							A
Maximum Forward Voltage at 1.5A DC	VF				1.1				V
Maximum DC Reverse Current@TJ=25℃at Rated DC Bolcking Voltage@TJ=125℃	lr	10 500							μA
I ² t Rating for Fusing (t<8.3ms)	l ² t	10.4						A ² s	
Typical Junction Capacitance Per Element (Note1)	Сл	25						pF	
Typical Thermal Resistance (Note2)	Reja	40						℃/W	
Operating Temperature Range	TJ	-55 to +150						°C	
Storage Temperature Range	Tstg	-55 to +150							°C
		1							1

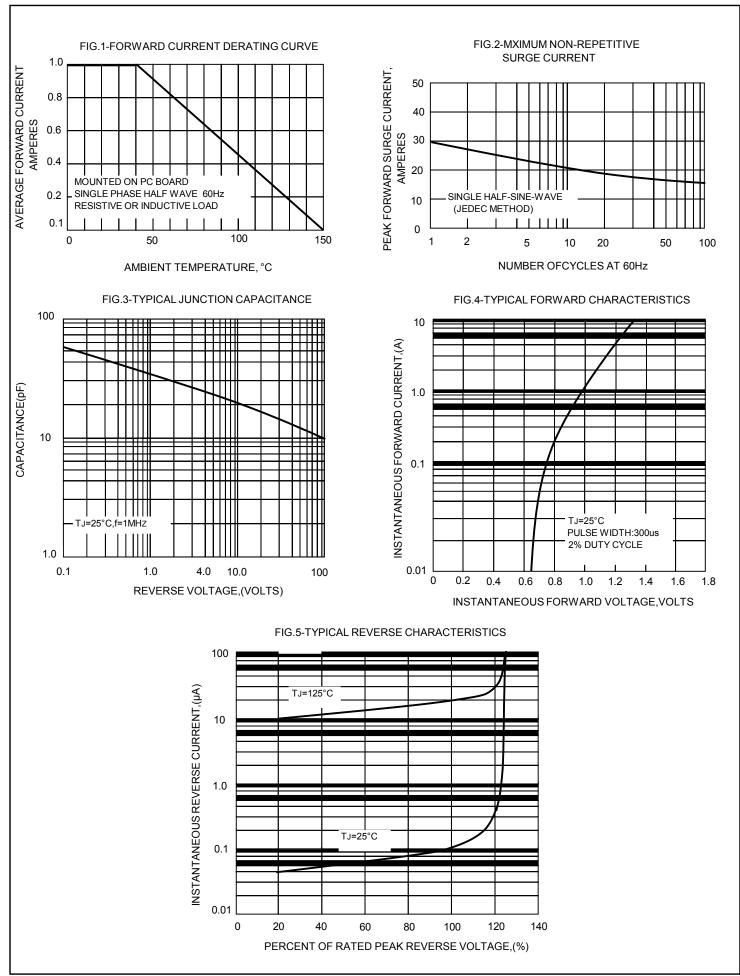
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Note:1.Measured at 1.0MHz and applied reverse voltage of 4.0V DC.

2. Thermal resistance from junction to ambient mounted on P.C.B.

with 0.5*0.5"(13*13mm) copper pads.

RATING AND CHARACTERISTIC CURVES DB151S thru DB157S



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